Power management (dual transistors) **EMF5**

2SA2018 and DTC144EE are housed independently in a EMT6 package.

Application

Power management circuit

Features

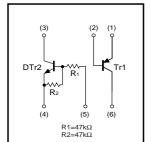
1) Power switching circuit in a single package.

2) Mounting cost and area can be cut in half.

Structure

Silicon epitaxial planar transistor

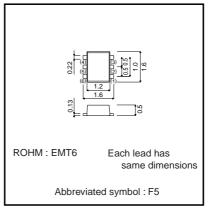
Equivalent circuits



Packaging specifications

| Туре | EMF5 |
|------------------------------|------|
| Package | EMT6 |
| Marking | F5 |
| Code | T2R |
| Basic ordering unit (pieces) | 8000 |

•Dimensions (Units : mm)



Transistors

●Absolute maximum ratings (Ta=25°C)

Tr1

| Parameter | Symbol | Limits | Unit |
|------------------------------|--------|------------|-------|
| Collector-base voltage | Vсво | -15 | V |
| Collector-emitter voltage | VCEO | -12 | V |
| Emitter-base voltage | Vebo | -6 | V |
| Collector current | lc | -500 | mA |
| Collector current | Іср | -1.0 | A *1 |
| Power dissipation | Pc | 150(TOTAL) | mW *2 |
| Junction temperature | Tj | 150 | °C |
| Range of storage temperature | Tstg | -55~+150 | °C |

*1 Single pulse Pw=1ms *2 120mW per element must not be exceeded. Each terminal mounted on a recommended land.

DTr2

| Parameter | Symbol | Limits | Unit |
|------------------------------|--------|------------|-------|
| Supply voltage | Vcc | 50 | V |
| Input voltage | Vin | -10~+40 | V |
| Collector current | lc | 100 | mA *1 |
| Output current | lo | 30 | mA |
| Power dissipation | Pc | 150(TOTAL) | mW *2 |
| Junction temperature | Tj | 150 | °C |
| Range of storage temperature | Tstg | -55~+150 | °C |

*1 Characteristics of built-in transistor.
 *2 120mW per element must not be exceeded. Each terminal mounted on a recommended land.

●Electrical characteristics (Ta=25°C)

Tr1

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|--------------------------------------|----------|------|------|------|------|----------------------------|
| Collector-emitter breakdown voltage | BVCEO | -12 | - | - | V | Ic=-1mA |
| Collector-base breakdown voltage | ВУсво | -15 | - | _ | V | Ic=-10μA |
| Emitter-base breakdown voltage | ВVево | -6 | - | - | V | Iε=-10μA |
| Collector cut-off current | Ісво | - | - | -100 | nA | Vсв=-15V |
| Emitter cut-off current | Іево | - | _ | -100 | nA | Veb=-6V |
| Collector-emitter saturation voltage | VCE(sat) | - | -100 | -250 | mV | Ic=-200mA, IB=-10mA |
| DC current gain | hfe | 270 | _ | 680 | _ | Vce=-2V, Ic=-10mA |
| Transition frequency | f⊤ | - | 260 | - | MHz | Vce=-2V, Ie=10mA, f=100MHz |
| Collector output capacitance | Cob | - | 6.5 | - | pF | Vcb=-10V, Ie=0mA, f=1MHz |

DTr2

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|----------------------|---------|------|------|------|------|------------------------------|
| Input voltage | VI(off) | - | - | 0.5 | V | Vcc=5V, Io=100μA |
| | VI(on) | 3.0 | - | - | V | Vo=0.3V, Io=2mA |
| Output voltage | VO(on) | - | 100 | 300 | mV | Vo=10mA, II=0.5mA |
| Input current | h | - | _ | 180 | μA | Vi=5V |
| Output current | IO(off) | - | - | 500 | nA | Vcc=50V, VI=0V |
| DC current gain | Gı | 68 | - | - | - | Vo=5V, Io=5mA |
| Transition frequency | f⊤ | - | 250 | - | MHz | Vce=10V, Ie=-5mA, f=100MHz * |
| Input resistance | R1 | 32.9 | 47 | 61.1 | kΩ | - |
| Resistance ratio | R2/R1 | 0.8 | 1.0 | 1.2 | - | - |

*Characteristics of built-in transistor.

Transistors

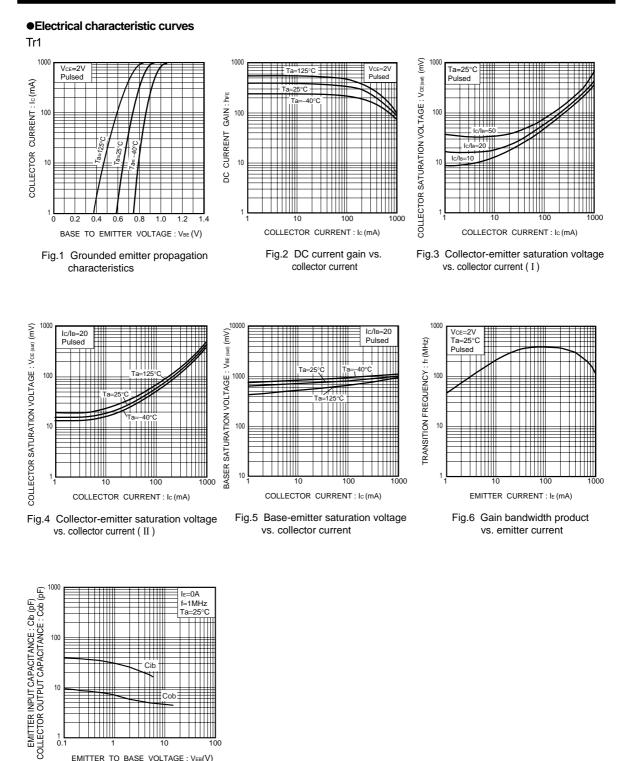


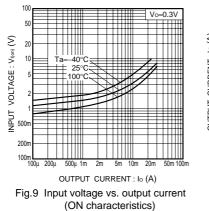
Fig.7 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage

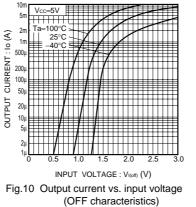
EMITTER TO BASE VOLTAGE : $\mathsf{V}_{\mathsf{EB}}(\mathsf{V})$

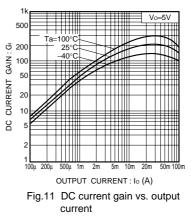
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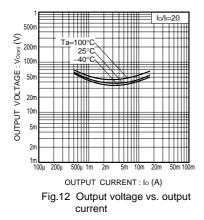
Transistors











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